NSN 5962-01-358-8680

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-358-8680 **Body Length:** 1.400 inches **Body Width:** 0.594 inches **Body Height:** 0.280 inches **Maximum Power Dissipation Rating:** 4.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and positive outputs **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 9 input **Current Rating Per Characteristic:** 50.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** 35.00 input picofarads and 40.00 output picofarads **Time Rating Per Chacteristic:** 85.00 nanoseconds delay **Memory Device Type:** First-in first-out **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a

--

Unit Of Measure:

NSN 5962-01-358-8680

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

A458a0